

TUNG-SOL

HEPTODE PENTAGRID CONVERTER

PHYSICAL SPECIFICATIONS

EMITTER COATED UNIPOT. CATHODE		PIN CONNECTIONS	
BASE	SMALL WAFER OCTAL 8-PIN	PIN 1 SHELL, GRID 5	PIN 7 HEATER
	PHENOLIC	PIN 2 HEATER	PIN 8 SIGNAL GRID G3
BULB	MT-8 METAL	PIN 3 PLATE	
MAXIMUM DIAMETER	1 5/16"	PIN 4 SCR. (G2 & G4)	MOUNTING POS. ANY
MAXIMUM OVERALL LENGTH	2 5/8"	PIN 5 OSC. GRID (G1)	
MAXIMUM SEATED HEIGHT	2 1/16"	PIN 6 CATHODE	

RATINGS

INTERPRETED ACCORDING TO RMA STANDARD MB-210

HEATER OR FILAMENT VOLTAGE (AC OR DC)	12.6 VOLTS
HEATER OR FILAMENT CURRENT	0.15 AMP.
MAXIMUM PLATE VOLTAGE	300 VOLTS
MAXIMUM SCREEN VOLTAGE	100 VOLTS
MAXIMUM SCREEN SUPPLY VOLTAGE	300 VOLTS
MAXIMUM PLATE DISSIPATION	1.0 WATT
MAXIMUM SCREEN DISSIPATION	1.0 WATT
MAXIMUM TOTAL PLATE AND SCREEN DISSIPATION	WATTS
MAXIMUM TOTAL CATHODE CURRENT	14 MA.
MINIMUM EXTERNAL SIGNAL GRID BIAS VOLTAGE ^A	0 VOLTS
MAXIMUM ANODE-GRID VOLTAGE	VOLTS
MAXIMUM ANODE-GRID SUPPLY VOLTAGE	VOLTS
MAXIMUM ANODE-GRID DISSIPATION	WATT

^A WITH SELF-EXCITED OSCILLATOR

CAPACITANCES

SIGNAL GRID TO MIXER PLATE (G3 TO P) ^B	0.13 μ f (MAX.)
K TO ALL OTHER ELECTRODES EXCEPT G1	5.0 μ f
SIGNAL GRID TO OSC. GRID (G3 TO G1) ^B	0.15 μ f (MAX.)
OSC. GRID TO MIXER PLATE (G1 TO P) ^B	0.06 μ f (MAX.)
SIGNAL INPUT (G3 TO ALL OTHER ELECTRODES) ^B	9.5 μ f
OSC. INPUT (G1 TO ALL OTHER ELECTRODES) ^B	7.0 μ f
G1 TO ALL OTHER ELECTRODES EXCEPT K	4.4 μ f
MIXER OUTPUT (P TO ALL OTHER ELECTRODES) ^B	12 μ f
G1 TO K	2.6 μ f

^B WITH SHIELD NO. 308 CONNECTED TO CATHODETYPICAL OPERATING CONDITIONS AND CHARACTERISTICS
CONVERTER SERVICE - SEPARATE EXCITATION

CHARACTERISTICS SHOWN ARE OBTAINED IN THE STANDARD RMA CONVERSION TRANSCONDUCTANCE TEST SET AND CORRESPOND VERY CLOSELY TO THOSE OBTAINED WITH ZERO BIAS IN A SELF-EXCITED OSCILLATOR CIRCUIT.

HEATER OR FILAMENT VOLTAGE	12.6	12.6	12.6 VOLTS
HEATER OR FILAMENT CURRENT	0.15	0.15	0.15 AMP.
PLATE VOLTAGE	28	100	250 VOLTS
SCREEN VOLTAGE	28	100	100 VOLTS
SIGNAL GRID BIAS	-1	-2	-2 VOLTS
ANODE-GRID VOLTAGE	0	0	0 VOLTS
PLATE CURRENT	0.5	3.5	3.5 MA.
SCREEN CURRENT	1.8	8.5	8.5 MA.
ANODE-GRID CURRENT			MA.
OSCILLATOR-GRID CURRENT	0.1	0.5	0.5 MA.
TOTAL CATHODE CURRENT	2.4	12.3	12.5 MA.
OSCILLATOR-GRID RESISTOR	20 000	20 000	20 000 OHMS
PLATE RESISTANCE (APPROX.)	---	0.5	1.0 MEGOHM

CONVERSION TRANSCONDUCTANCE

SIGNAL GRID BIAS $\approx$ -1	250	---	---	μ MHOS
SIGNAL GRID BIAS $\approx$ -2	---	425	---	450 μ MHOS
SIGNAL GRID BIAS $\approx$ -6	8	310	325	μ MHOS
SIGNAL GRID BIAS $\approx$ -10	---	75	80	μ MHOS
SIGNAL GRID BIAS $\approx$ -35	---	2	2	μ MHOS APPROX.

NOTE: WITH G2 & G4 CONNECTED TO PLATE (100 VOLTS), AND SIGNAL APPLIED TO G1 (0 VOLTS BIAS): THE TRANSCONDUCTANCE IS 4500 μ MHOS, THE PLATE CURRENT IS 27 MA., AND THE AMPLIFICATION IS 13. G3 IS CONNECTED TO GROUND DURING THIS TEST.